

Novel BaTiO₃-based, Ag/Pd compatible lead-free relaxors with superior energy storage performance

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Supporting information

Novel BaTiO₃-based, Ag/Pd compatible lead-free relaxors

with superior energy storage performance

Huijing Yang^{a,b#}, Zhilun Lu^{a#}, Linhao Li^{a#}, Weichao Bao^{c#}, Hongfen Ji^{a,d}, Jinglei Li^e, Antonio Feteira^f, Fangfang Xu^c, Yong Zhang^g, Huajun Sun^g, Zhichao Huang^{f,h}, Weichao Lou^{f,h}, Kaixin Song^h, Shikuan Sun^a, Ge Wang^{a*}, Dawei Wang^{a*}, Ian M. Reaney^a

^aDepartment of Materials Science and Engineering, University of Sheffield, Sheffield, S1 3JD, UK

^bDepartment of Physics, Tangshan Normal University, Tangshan, 063000, China

^cState Key Laboratory of High Performance Ceramics and Superfine Microstructure, Shanghai Institute of Ceramics, Shanghai, 200050, China

^dLaboratory of Thin Film Techniques and Optical Test, Xi'an Technological University, Xi'an, 710032, China

^eElectronic Materials Research Laboratory, Key Laboratory of the Ministry of Education and International Center for Dielectric Research, Xi'an Jiaotong University, Xi'an, 710049, China.

^fMaterials and Engineering Research Institute, Sheffield Hallam University, Sheffield, S1 1WB, UK

^gState Key Laboratory of Silicate Materials for Architectures, School of Materials Science and Engineering, Wuhan University of Technology, Wuhan, 430070, China.

^hCollege of Electronics Information, Hangzhou Dianzi University, Hangzhou, 310018, China

*Corresponding authors. E-mail address: g.wang@sheffield.ac.uk, dawei.wang@sheffield.ac.uk

#Author Contributions: H. Y., Z. L., L. Li. and W. Bao contributed equally to this work.

Figure S-1. Full-pattern refinement of $x\text{B}_{2/3}\text{MN-BT}$ ceramics

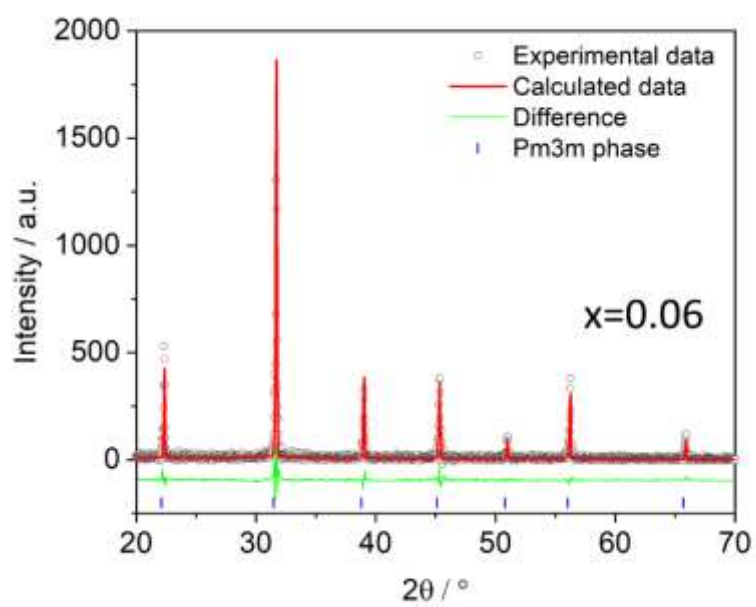


Figure S-2. P-E loop for BT ceramics at 60 kV cm^{-1}

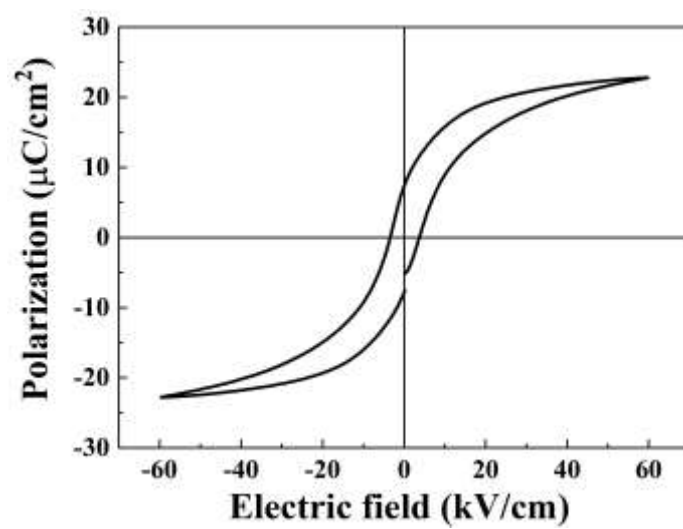


Figure S-3. (a-f) The frequency-dependent dielectric properties for $x\text{B}_{2/3}\text{MN-BT}$ ($x=0.00 \leq x \leq 0.10$) ceramics.

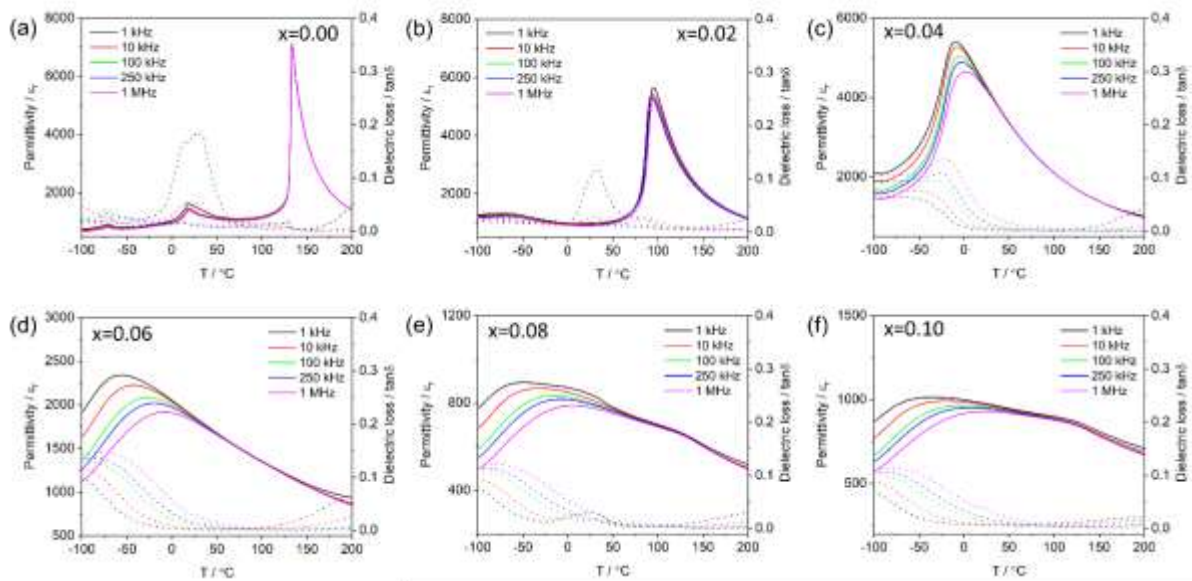


Figure S-4. (a-f) The SEM image of thermal-etched surfaces for $x\text{B}_{2/3}\text{MN-BT}$ ($x=0.00 \leq x \leq 0.10$) ceramics.

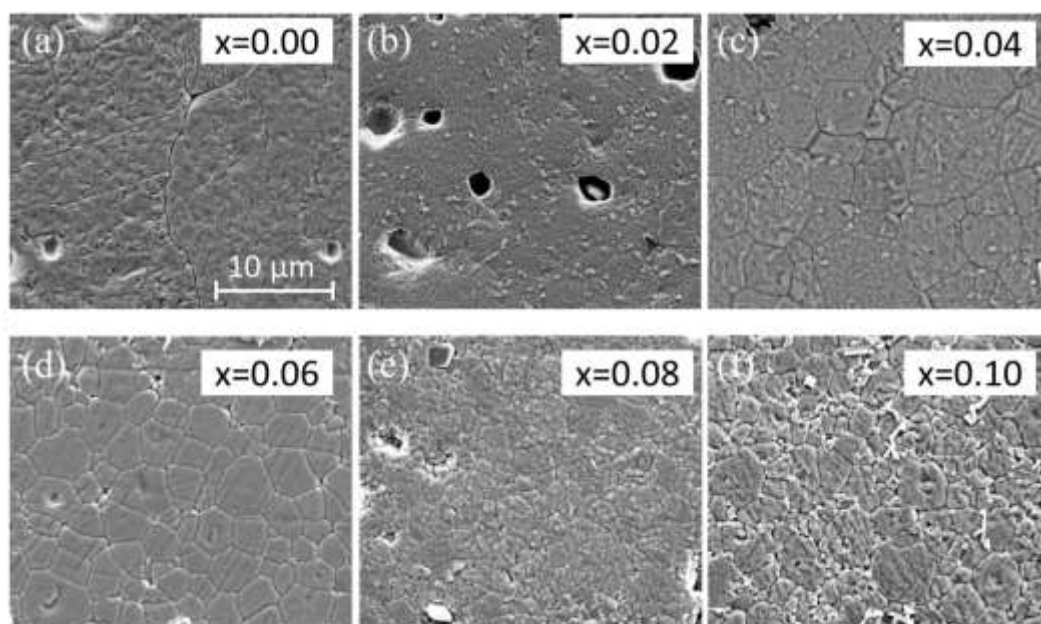


Figure S-5. (a-d) Unipolar P-E loops under E_{\max} and (e-h) calculated energy storage properties (W_{rec} and η) at different electric field for $x\text{B}_{2/3}\text{MN-BT}$ ceramics.

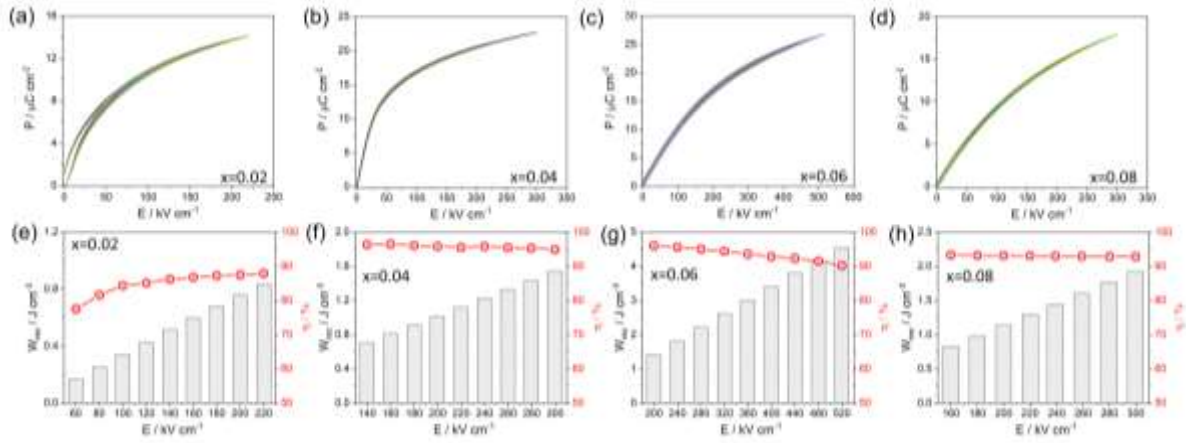


Figure S-6. (a) Changes of E_{\max} and ΔP for $x\text{B}_{2/3}\text{MN-BT}$ ceramics. (b) Change of W_{rec} and η as function of x concentration.

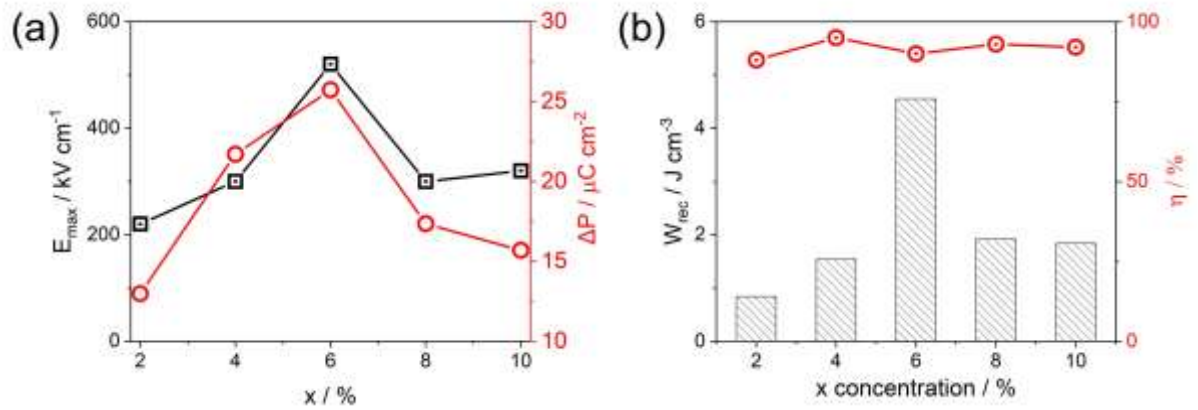


Table S-1. Refined crystallography details for BT-xB_{2/3}MN ceramics.

Composition / x	0.00		0.02	0.04	0.06
GOF	1.31	2.19	1.34	1.55	1.86
R _{exp}	9.03	16.25	6.75	7.79	8.02
R _{wp}	11.84	39.59	9.08	12.05	14.99
Space group	<i>P4mm</i>	<i>Pm3m</i>	<i>P4mm</i>	<i>Pm3m</i>	<i>Pm3m</i>
Cell mass	233.19	234.642	233.57	234.64	235.73
Cell volume	64.40(4)	64.49(4)	64.52(7)	64.69(4)	64.93(4)
Crystal density	6.013(4)	6.023(4)	6.018(8)	6.023(4)	6.029(9)
Lattice parameter a / Å	3.9946(12)	4.0144(8)	3.9901(13)	4.0144(8)	4.0192(8)
Lattice parameter c / Å	4.0358(12)	N/A	4.0211(8)	N/A	N/A
c/a ratio	1.0103	N/A	1.0083	N/A	N/A

Refined atoms position details								
	site	NP	x	y	z	Atom	Occ	Beq
0.00	Ba	1	0.0000	0.0000	0.0000	Ba+2	1.000	0.012
	Ti	1	0.5000	0.5000	0.5370	Ti+4	1.000	0.019
	O1	1	0.50000	0.5000	-0.3700	O-2	1.000	0.062
	O2	2	0.5000	0.00000	0.5180	O-2	1.000	0.042
0.02	Ba	1	0.0000	0.0000	0.0000	Ba+2	0.980	0.025
						Bi+3	0.013	0.025
	Ti	1	0.5000	0.5000	0.5370	Ti+4	0.980	0.033
						Mg+2	0.007	0.033
						Nb+5	0.013	0.033
	O1	1	0.5000	0.5000	-0.3700	O-2	1.000	0.051
0.04	O2	2	0.5000	0.0000	0.5180	O-2	1.000	0.033
	Ba	1	0.0000	0.0000	0.0000	Ba+2	0.960	0.015
						Bi+3	0.027	0.015
	Ti	1	0.5000	0.5000	0.5000	Ti+4	0.960	0.015
						Mg+2	0.013	0.015
						Nb+5	0.027	0.015
0.06	O1	3	0.0000	0.5000	0.5000	O-2	1.000	0.004
	Ba	1	0.0000	0.0000	0.0000	Ba+2	0.940	0.022
						Bi+3	0.040	0.022
	Ti	1	0.5000	0.5000	0.5000	Ti+4	0.940	0.025
						Mg+2	0.020	0.025
						Nb+5	0.040	0.025
0.06	O1	3	0000	0.5000	0.5000	O-2	1.000	0.012

Table S-2. Average grain size for $x\text{B}_{2/3}\text{MN-BT}$ ceramics

Composition	Average grain size / μm
x=0.00	25.2 ± 0.6
x=0.02	16.6 ± 0.5
x=0.04	7.2 ± 0.6
x=0.06	2.8 ± 0.3
x=0.08	2.4 ± 0.5
x=0.10	2.3 ± 0.4